

# PC924

## OPIC Photocoupler for IGBT Drive of Inverter

\* Lead forming type ( I type ) and taping reel type ( P type ) are also available. ( PC924I/PC924P )

\*\* TÜV ( VDE 0884 ) approved type is also available as an option.

### ■ Features

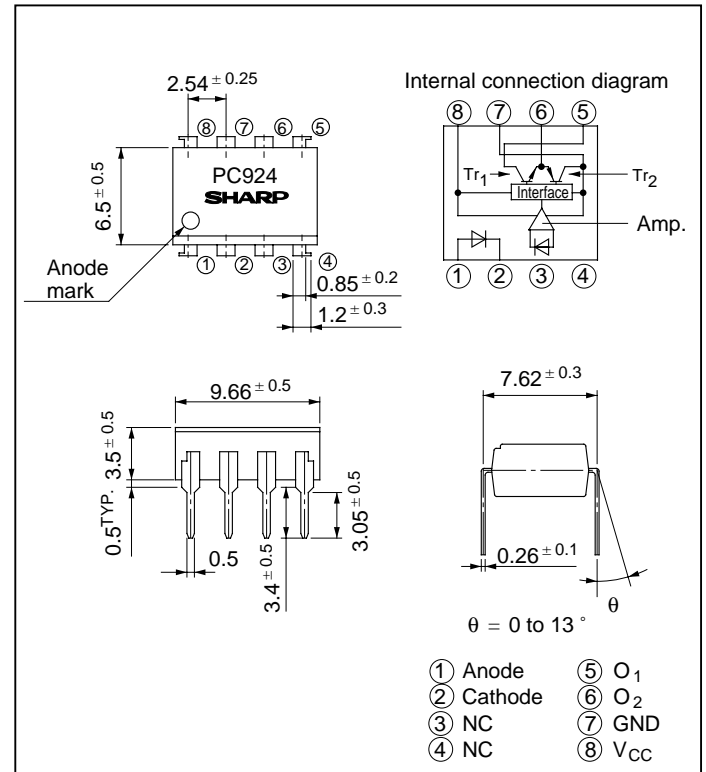
1. Built-in direct drive circuit for IGBT drive  
(  $I_{O1P}, I_{O2P} : 0.4A$  )
2. High speed response (  $t_{PLH}, t_{PHL} : \text{MAX. } 2.0 \mu s$  )
3. Wide operating supply voltage range  
(  $V_{CC} : 15 \text{ to } 30V$  at  $T_a = -10 \text{ to } 60^\circ C$  )
4. High noise resistance type  
 $CM_H : \text{MIN. } -1500V/\mu s$   
 $CM_L : \text{MIN. } 1500V/\mu s$
5. High isolation voltage (  $V_{iso} : 5000V_{rms}$  )

### ■ Applications

1. IGBT drive for inverter control

### ■ Outline Dimensions

( Unit : mm )



\* "OPIC" (Optical IC) is a trademark of the SHARP Corporation.

An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

### ■ Absolute Maximum Ratings

(Unless specified,  $T_a = T_{opr}$ )

	Parameter	Symbol	Rating	Unit
Input	Forward current	$I_F$	25	mA
	Reverse voltage	$V_R$	6	V
Output	Supply voltage	$V_{CC}$	35	V
	O <sub>1</sub> output current	$I_{O1}$	0.1	A
	*1 O <sub>1</sub> peak output current	$I_{O1P}$	0.4	A
	O <sub>2</sub> output current	$I_{O2}$	0.1	A
	*1 O <sub>2</sub> peak output current	$I_{O2P}$	0.4	A
	O <sub>1</sub> output voltage	$V_{O1}$	35	V
	Power dissipation	$P_O$	500	mW
	Total power dissipation	$P_{tot}$	550	mW
	*2 Isolation voltage	$V_{iso}$	5000	$V_{rms}$
	Operating temperature	$T_{opr}$	- 25 to + 80	°C
	Storage temperature	$T_{stg}$	- 55 to + 125	°C
	*3 Soldering temperature	$T_{sol}$	260	°C

\*1 Pulse width  $\leq 0.15 \mu s$ ,  
Duty ratio : 0.01

\*2 40 to 60% RH, AC for  
1 minute,  $T_a = 25^\circ C$

\*3 For 10 seconds

## ■ Electro-optical Characteristics

( Ta = T<sub>opr</sub> unless otherwise specified )

Parameter		Symbol	*4 Conditions	MIN.	TYP.	MAX.	Unit	Fig.			
Input	Forward voltage	V <sub>F1</sub>	Ta = 25°C, I <sub>F</sub> = 20mA	-	1.2	1.4	V	-			
		V <sub>F2</sub>	Ta = 25°C, I <sub>F</sub> = 0.2mA	0.6	0.9	-	V	-			
	Reverse current	I <sub>R</sub>	Ta = 25°C, V <sub>R</sub> = 4V	-	-	10	μA	-			
	Terminal capacitance	C <sub>t</sub>	Ta = 25°C, V = 0, f = 1kHz	-	30	250	pF	-			
Output	Operating supply voltage	V <sub>CC</sub>	Ta = - 10 to 60°C	15	-	30	V	-			
				15	-	24	V				
	O <sub>1</sub> low level output voltage	V <sub>O1L</sub>	V <sub>CC1</sub> = 12V, V <sub>CC2</sub> = - 12V I <sub>O1</sub> = 0.1A, I <sub>F</sub> = 10mA	-	0.2	0.4	V	1			
	O <sub>2</sub> high level output voltage	V <sub>O2H</sub>	V <sub>CC</sub> = V <sub>O1</sub> = 24V, I <sub>O2</sub> = - 0.1A, I <sub>F</sub> = 10mA	18	21	-	V	2			
	O <sub>2</sub> low level output voltage	V <sub>O2L</sub>	V <sub>CC</sub> = 24V, I <sub>O2</sub> = 0.1A, I <sub>F</sub> = 0	-	1.2	2.0	V	3			
	O <sub>1</sub> leak current	I <sub>O1L</sub>	Ta = 25°C, V <sub>CC</sub> = V <sub>O1</sub> = 35V, I <sub>F</sub> = 0	-	-	500	μA	4			
	O <sub>2</sub> leak current	I <sub>O2L</sub>	Ta = 25°C, V <sub>CC</sub> = V <sub>O2</sub> = 35V, I <sub>F</sub> = 10mA	-	-	500	μA	5			
	High level supply current	I <sub>CCH</sub>	Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA	-	6	10	mA	6			
			V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA	-	-	14	mA				
Low level supply current	I <sub>CCL</sub>	Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 0	-	8	13	mA	6				
		V <sub>CC</sub> = 24V, I <sub>F</sub> = 0	-	-	17	mA					
Transfer characteristics	*5 “Low→High” threshold input current	I <sub>FLH</sub>	Ta = 25°C, V <sub>CC</sub> = 24V	1.0	4.0	7.0	mA	7			
			V <sub>CC</sub> = 24V	0.6	-	10.0	mA				
	Isolation resistance	R <sub>ISO</sub>	Ta = 25°C, DC = 500V, 40 to 60% RH	5 × 10 <sup>10</sup>	10 <sup>11</sup>	-	Ω	-			
	Response time			Ta = 25°C, V <sub>CC</sub> = 24V, I <sub>F</sub> = 10mA R <sub>C</sub> = 47Ω, C <sub>G</sub> = 3,000pF	“Low→High” propagation delay time	t <sub>PLH</sub>	-	1.0	2.0	μs	8
					“High→Low” propagation delay time	t <sub>PHL</sub>	-	1.0	2.0	μs	
					Rise time	t <sub>r</sub>	-	0.2	0.5	μs	
					Fall time	t <sub>f</sub>	-	0.2	0.5	μs	
	Instantaneous common mode rejection voltage “Output: High level”	CM <sub>H</sub>	Ta = 25°C, V <sub>CM</sub> = 600V(peak) I <sub>F</sub> = 10mA, V <sub>CC</sub> = 24V, ΔV <sub>O2H</sub> = 2.0V	-	- 30	-	kV/μs	9			
Instantaneous common mode rejection voltage “Output: Low level”	CM <sub>L</sub>	Ta = 25°C, V <sub>CM</sub> = 600V(peak) I <sub>F</sub> = 0, V <sub>CC</sub> = 24V, ΔV <sub>O2L</sub> = 2.0V	-	30	-	kV/μs					

\*4 When measuring output and transfer characteristics, connect a by-pass capacitor ( 0.01 μF or more ) between V<sub>CC</sub> and GND near the device.

\*5 I<sub>FLH</sub> represents forward current when output goes from “Low” to “High” .

## ■ Truth Table

Input	O <sub>2</sub> Output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

■ Test Circuit

Fig. 1

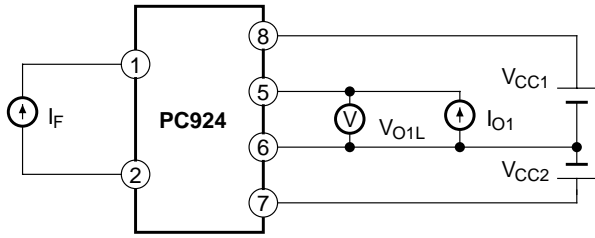


Fig. 2

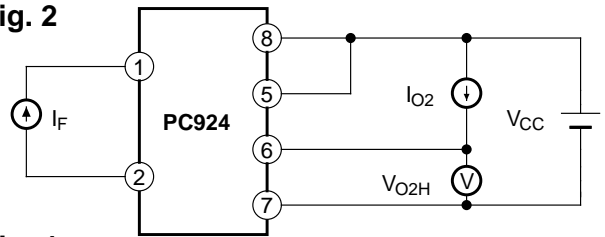


Fig. 3

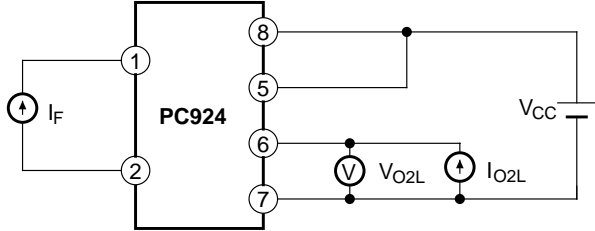


Fig. 4

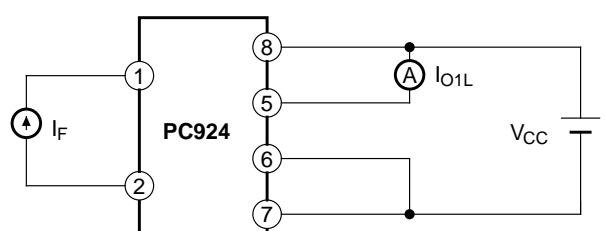


Fig. 5

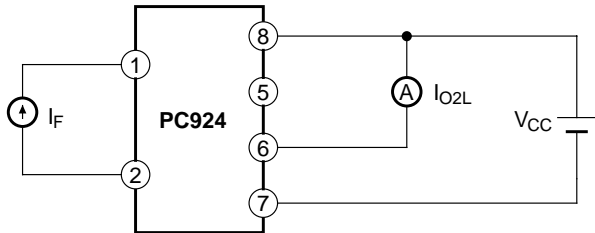


Fig. 6

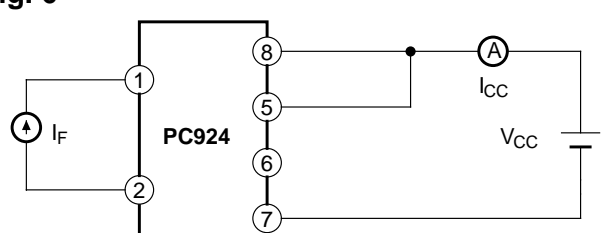


Fig. 7

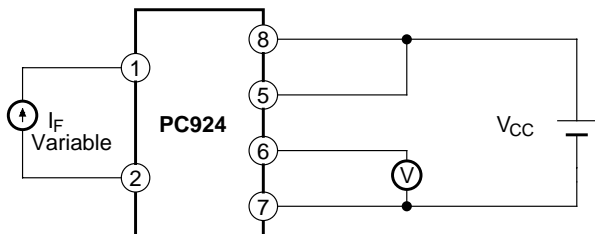


Fig. 8

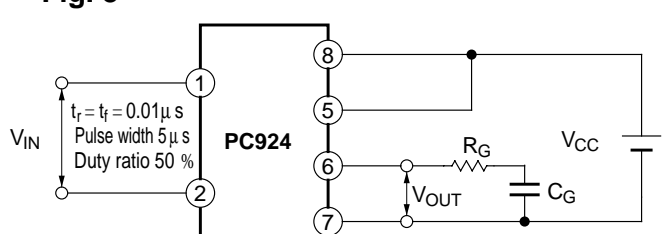
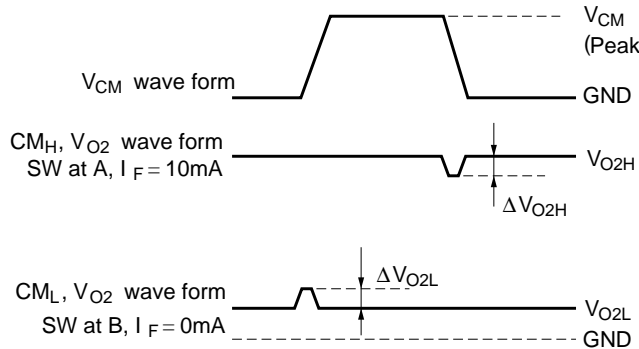
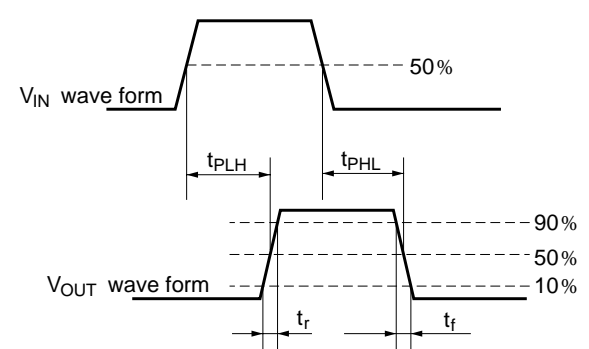
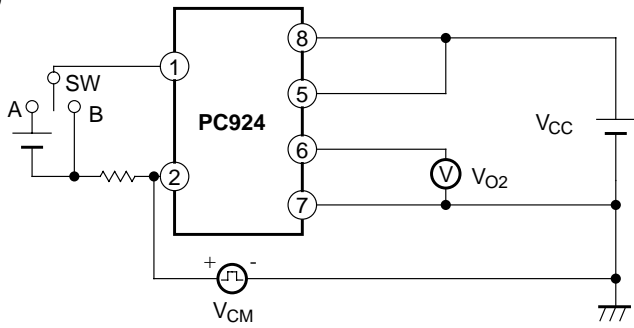
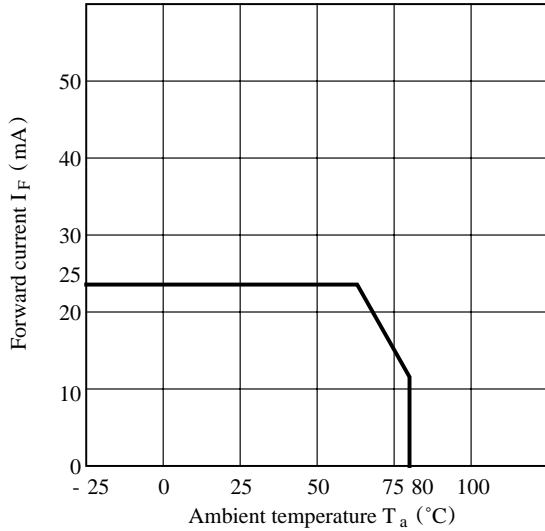


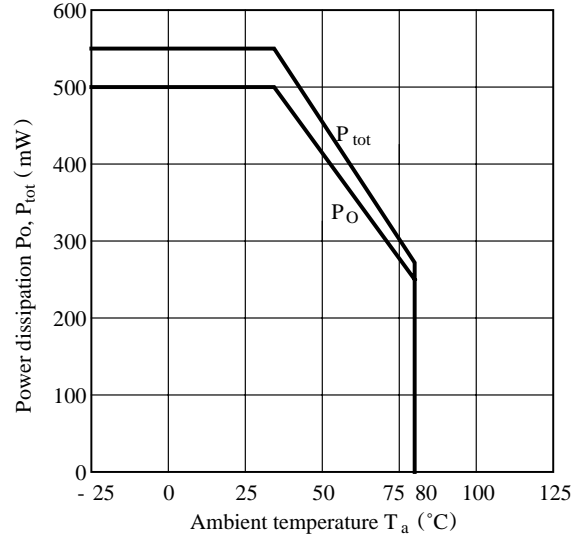
Fig. 9



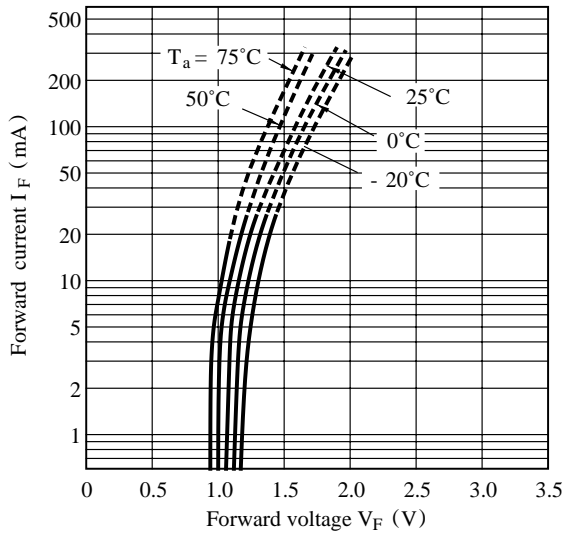
**Fig.10 Forward Current vs. Ambient Temperature**



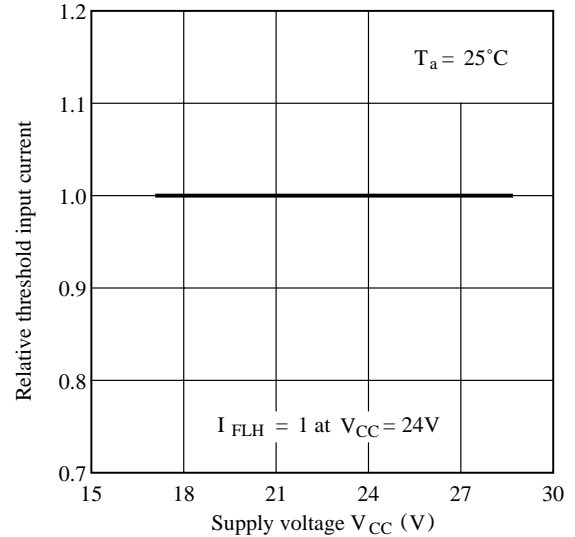
**Fig.11 Power Dissipation vs. Ambient Temperature**



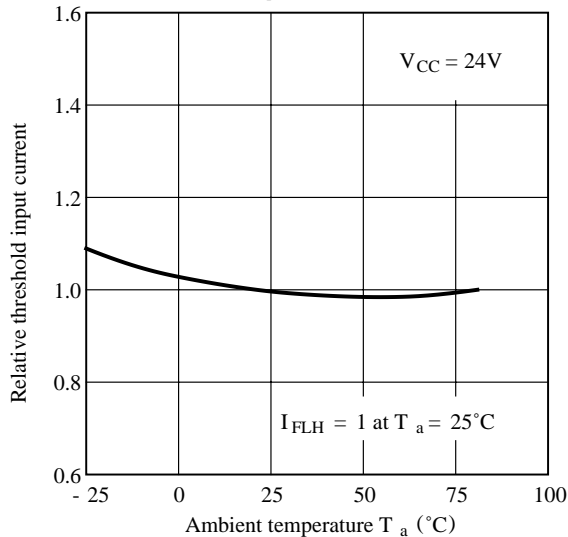
**Fig.12 Forward Current vs. Forward Voltage**



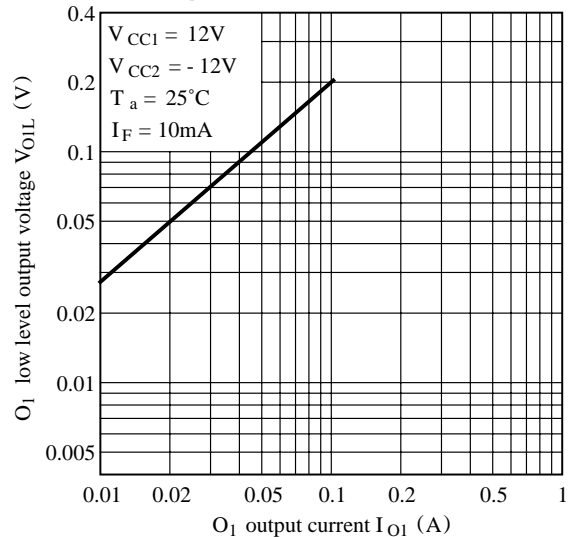
**Fig.13 Relative Threshold Input Current vs. Supply Voltage**



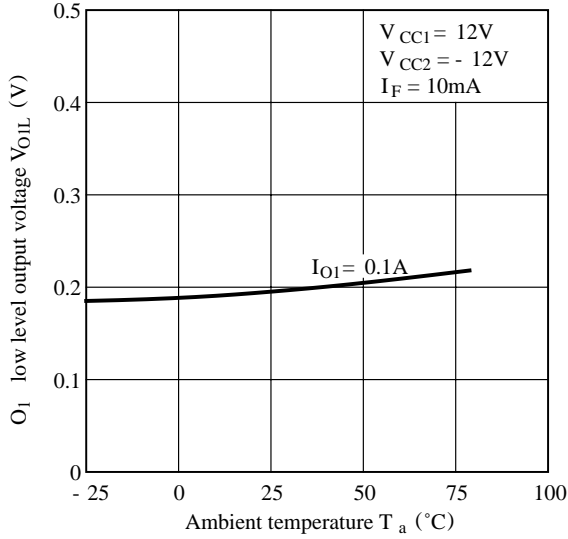
**Fig.14 Relative Threshold Input Current vs. Ambient Temperature**



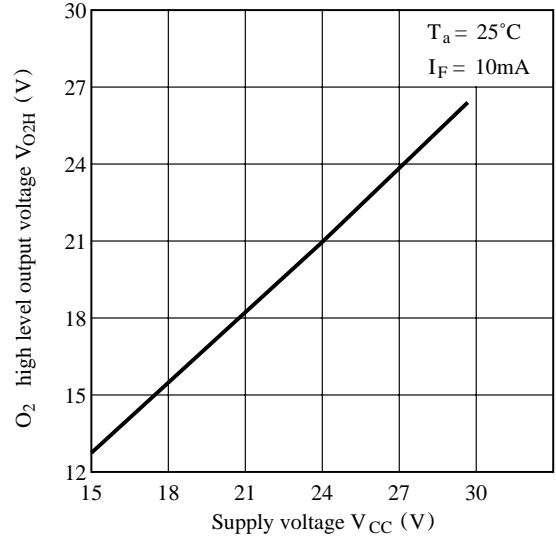
**Fig.15 O\_1 Low Level Output Voltage vs. O\_1 Output Current**



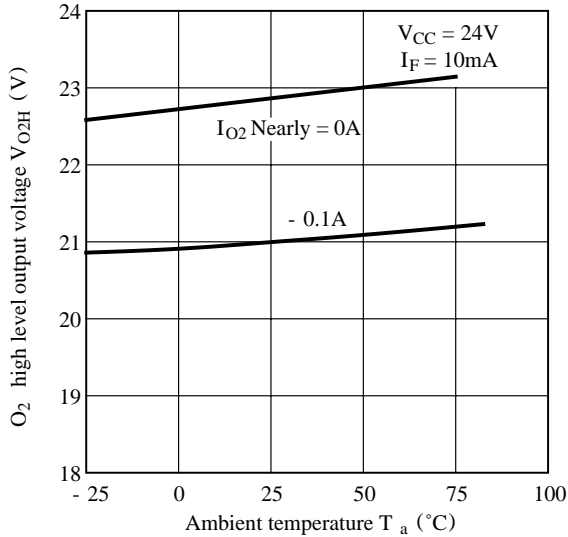
**Fig.16 O<sub>1</sub> Low Level Output Voltage vs. Ambient Temperature**



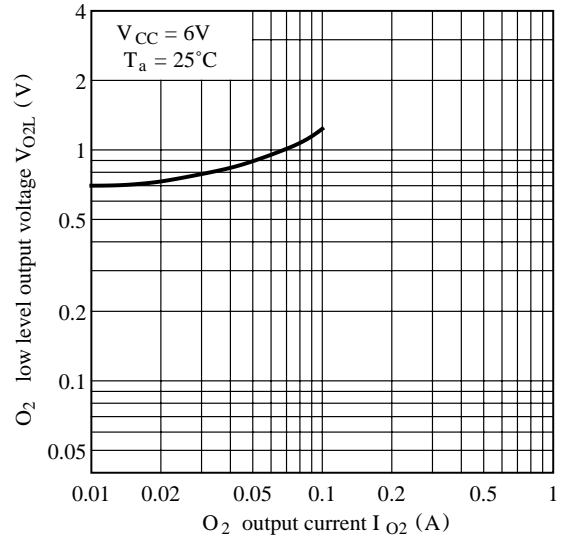
**Fig.17 O<sub>2</sub> High Level Output Voltage vs. Supply Voltage**



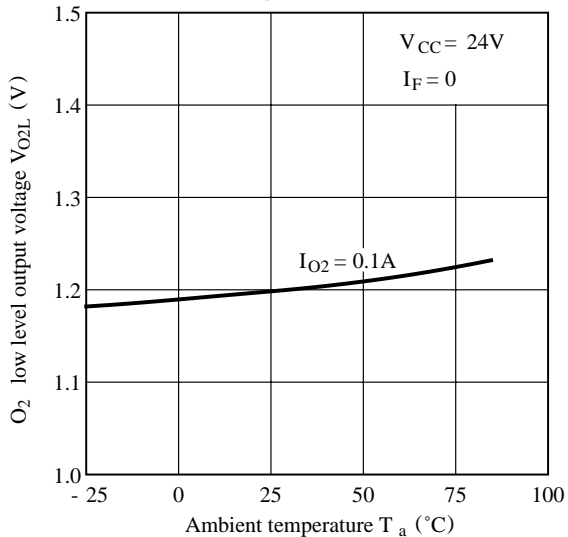
**Fig.18 O<sub>2</sub> High Level Output Voltage vs. Ambient Temperature**



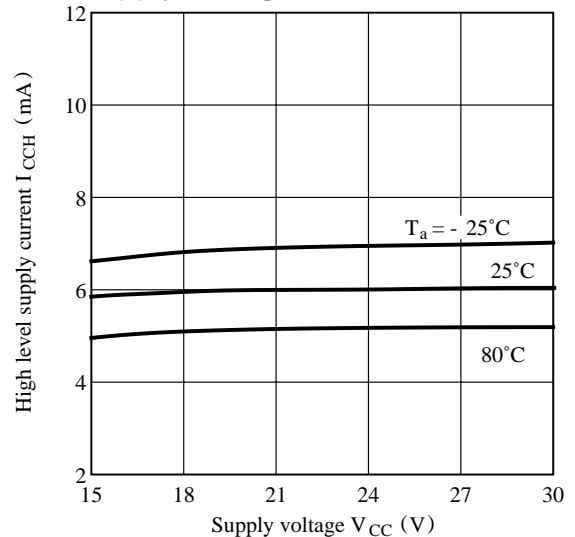
**Fig.19 O<sub>2</sub> Low Level Output Voltage vs. O<sub>2</sub> Output Current**



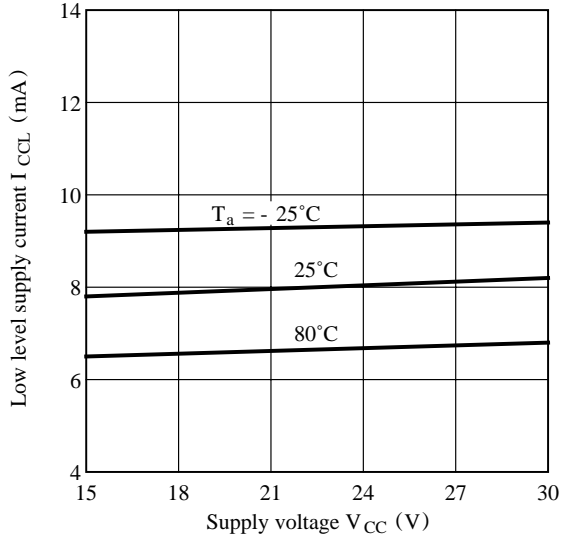
**Fig.20 O<sub>2</sub> Low Level Output Voltage vs. Ambient Temperature**



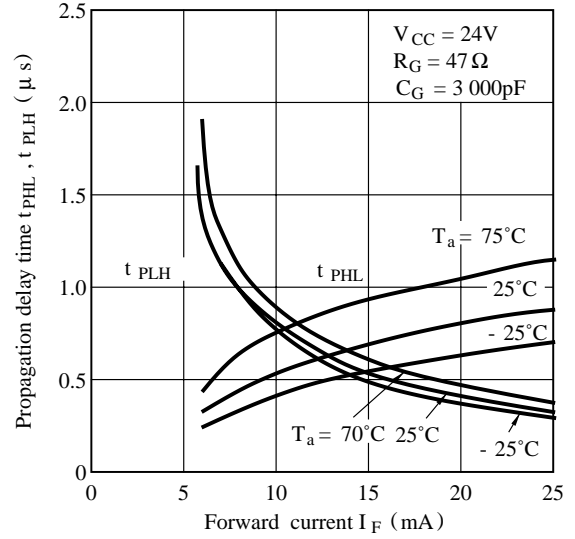
**Fig.21 High Level Supply Current vs. Supply Voltage**



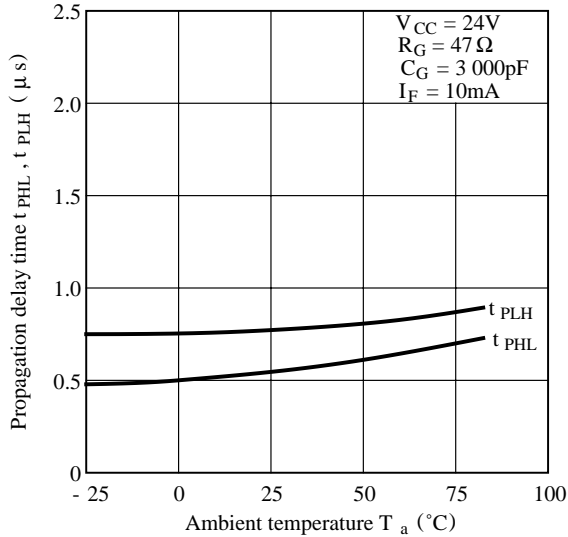
**Fig.22 Low Level Supply Current vs. Supply Voltage**



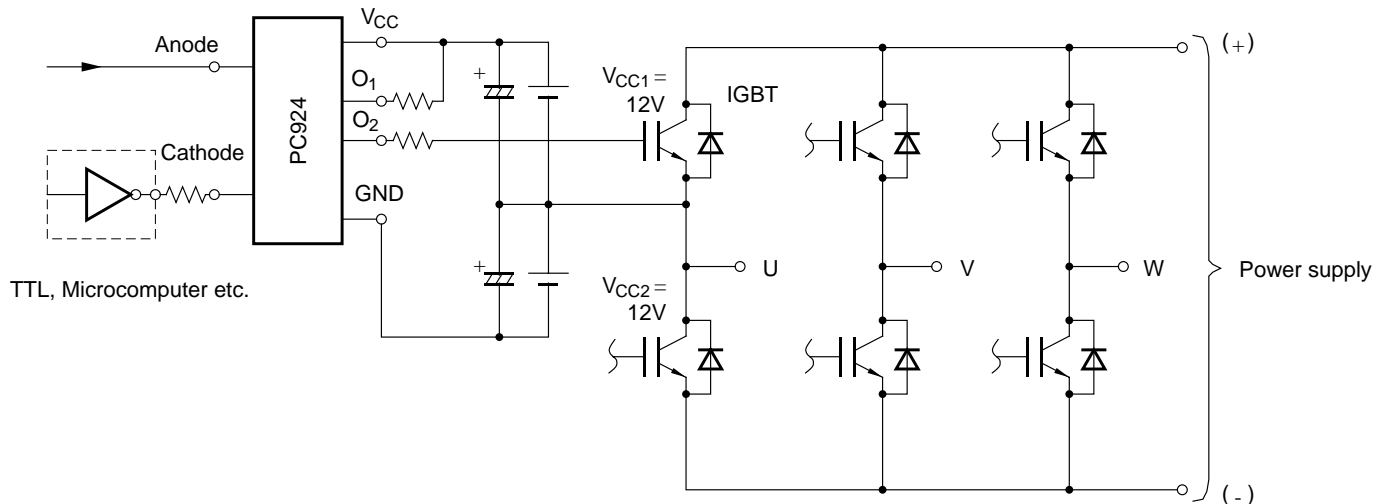
**Fig.23 Propagation Delay Time vs. Forward Current**



**Fig.24 Propagation Delay Time vs. Ambient Temperature**



■ Application Circuit (IGBT Drive for Inverter)



● Please refer to the chapter “Precautions for Use”